SN54AHC374, SN74AHC374 OCTAL EDGE-TRIGGERED D-TYPE FLIP-FLOPS WITH 3-STATE OUTPUTS

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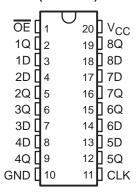
- **EPIC™** (Enhanced-Performance Implanted **CMOS) Process**
- Operating Range 2-V to 5.5-V V_{CC}
- 3-State Outputs Drive Bus Lines Directly
- Latch-Up Performance Exceeds 250 mA Per **JESD 17**
- **ESD Protection Exceeds 2000 V Per** MIL-STD-883, Method 3015; Exceeds 200 V Using Machine Model (C = 200 pF, R = 0)
- **Package Options Include Plastic** Small-Outline (DW), Shrink Small-Outline (DB), Thin Very Small-Outline (DGV), Thin Shrink Small-Outline (PW), and Ceramic Flat (W) Packages, Ceramic Chip Carriers (FK), and Standard Plastic (N) and Ceramic (J) DIPs

description

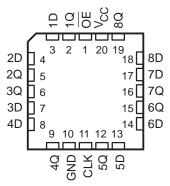
The 'AHC374 devices are octal edge-triggered D-type flip-flops that feature 3-state outputs designed specifically for driving highly capacitive or relatively low-impedance loads. These devices are particularly suitable for implementing buffer registers, I/O ports, bidirectional bus drivers, and working registers.

On the positive transition of the clock (CLK) input, the Q outputs are set to the logic levels of the data (D) inputs.

SN54AHC374 . . . J OR W PACKAGE SN74AHC374 . . . DB, DGV, DW, N, OR PW PACKAGE (TOP VIEW)



SN54AHC374 . . . FK PACKAGE (TOP VIEW)



A buffered output-enable (\overline{OE}) input can be used to place the eight outputs in either a normal logic state (high or low) or the high-impedance state. In the high-impedance state, the outputs neither load nor drive the bus lines significantly. The high-impedance state and the increased drive provide the capability to drive bus lines without interface or pullup components.

OE does not affect internal operations of the flip-flop. Old data can be retained or new data can be entered while the outputs are in the high-impedance state.

To ensure the high-impedance state during power up or power down, $\overline{\sf OE}$ should be tied to ${\sf V}_{\sf CC}$ through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

The SN54AHC374 is characterized for operation over the full military temperature range of -55°C to 125°C. The SN74AHC374 is characterized for operation from -40°C to 85°C.



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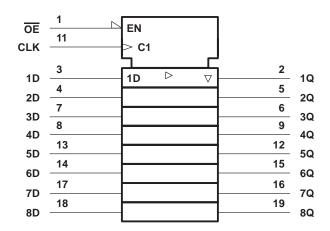
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FUNCTION TABLE (each flip-flop)

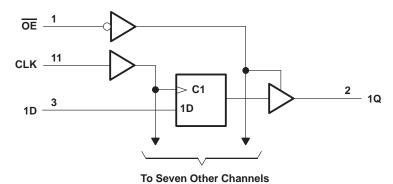
	INPUTS		OUTPUT
OE	CLK	D	Q
L	\uparrow	Н	Н
L	\uparrow	L	L
L	H or L	Χ	Q ₀
Н	Χ	Χ	Z

logic symbol†



[†] This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.

logic diagram (positive logic)





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absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

Supply voltage range, V _{CC}		–0.5 V to 7 V
Input voltage range, V _I (see Note 1)		0.5 V to 7 V
Output voltage range, VO (see Note 1)		\dots -0.5 V to V _{CC} + 0.5 V
Input clamp current, I_{IK} ($V_I < 0$)		–20 mA
Output clamp current, IOK (VO < 0 or VO > VO	cc)	±20 mA
Continuous output current, $I_O(V_O = 0 \text{ to } V_{CC})$		
Continuous current through V _{CC} or GND		
Package thermal impedance, θ _{JA} (see Note 2	e): DB package	70°C/W
5	DGV package	92°C/W
	DW package	58°C/W
	N package	
	PW package	83°C/W
Storage temperature range, T _{stg}		–65°C to 150°C

[†] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTES: 1. The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

2. The package thermal impedance is calculated in accordance with JESD 51.

recommended operating conditions (see Note 3)

			SN54A	HC374	SN74A	HC374	UNIT	
			2 5.5 1.5 2.1 3.85 0.5 0.5 0.5 0 VCC -50 -2 -50 -2 -8	MAX	MIN	MAX	UNII	
Vcc	Supply voltage		2	5.5	2	5.5	V	
		V _{CC} = 2 V	1.5		1.5			
V_{IH}	High-level input voltage	V _{CC} = 3 V	2.1		2.1		V	
VIH VIL VI VO IOH		V _{CC} = 5.5 V	3.85		3.85			
		V _{CC} = 2 V		0.5		0.5		
	Low-level input voltage	V _{CC} = 3 V		0.9		0.9	V	
		V _{CC} = 5.5 V		1.65		1.65		
VI	Input voltage		0	5.5	0	5.5	V	
٧o	Output voltage		0	Vcc	0	Vcc	V	
		V _{CC} = 2 V		-50		-50	μΑ	
ІОН	High-level output current	$V_{CC} = 3.3 \text{ V} \pm 0.3 \text{ V}$		-4		-4	4	
		$V_{CC} = 5 V \pm 0.5 V$		-8		2 5.5 .5	mA	
		V _{CC} = 2 V		50		50	μΑ	
I_{OL}	Low-level output current	$V_{CC} = 3.3 \text{ V} \pm 0.3 \text{ V}$		4		4		
		$V_{CC} = 5 V \pm 0.5 V$		8		8	mA	
A+/A>4	Input transition rise or fall rate	$V_{CC} = 3.3 \text{ V} \pm 0.3 \text{ V}$		100		100	ns/V	
Δι/Δ۷	Input transition rise or fall rate $V_{CC} = 5 \text{ V} \pm 0.5 \text{ V}$			20		20	115/ V	
TA	Operating free-air temperature		-55	125	-40	85	°C	

NOTE 3: All unused inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.



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electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS	Vaa	T,	4 = 25°C	;	SN54A	HC374	SN74AI	UNIT	
PARAMETER	TEST CONDITIONS	VCC	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNIT
		2 V	1.9	2		1.9		1.9		
	I _{OH} = -50 μA	3 V	2.9	3		2.9		2.9		
VOH		4.5 V	4.4	4.5		4.4		4.4		V
	I _{OH} = -4 mA	3 V	2.58			2.48		2.48		
	I _{OH} = -8 mA	4.5 V	3.94			3.8		3.8		
		2 V			0.1		0.1		0.1	
	I _{OL} = 50 μA	3 V			0.1		0.1		0.1	
VOL		4.5 V			0.1		0.1		0.1	V
	I _{OL} = 4 mA	3 V			0.36		0.5		0.44	
	I _{OL} = 8 mA	4.5 V			0.36		0.5		0.44	
lį	V _I = V _{CC} or GND	0 V to 5.5 V			±0.1		±1*		±1	μΑ
loz	$V_O = V_{CC}$ or GND	5.5 V			±0.25		±2.5		±2.5	μΑ
ICC	$V_I = V_{CC}$ or GND, $I_O = 0$	5.5 V			4		40		40	μΑ
Ci	V _I = V _{CC} or GND	5 V		4	10				10	pF
Co	$V_O = V_{CC}$ or GND	5 V		6						pF

^{*} On products compliant to MIL-PRF-38535, this parameter is not production tested at $V_{CC} = 0 \text{ V}$.

timing requirements over recommended operating free-air temperature range, V_{CC} = 3.3 V \pm 0.3 V (unless otherwise noted) (see Figure 1)

		$T_A = 2$	T _A = 25°C		SN54AHC374		SN74AHC374	
		MIN	MAX	MIN	MAX	MIN	MAX	UNIT
t _W	Pulse duration, CLK high or low	5		5.5		5.5		ns
t _{su}	Setup time, data before CLK↑	4.5		4		4		ns
th	Hold time, data after CLK↑	2		2		2		ns

timing requirements over recommended operating free-air temperature range, V_{CC} = 5 V \pm 0.5 V (unless otherwise noted) (see Figure 1)

		T _A = 25°C		SN54AHC374		SN74AHC374		UNIT
		MIN	MAX	MIN	MAX	MIN	MAX	UNIT
t _W	Pulse duration, CLK high or low	5		5		5		ns
t _{su}	Setup time, data before CLK↑	3		3		3		ns
th	Hold time, data after CLK↑	2		2		2		ns

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switching characteristics over recommended operating free-air temperature range, V_{CC} = 3.3 V \pm 0.3 V (unless otherwise noted) (see Figure 1)

DADAMETER	FROM	то	LOAD	T,	4 = 25°C	;	SN54A	HC374	SN74AI	HC374	UNIT	
PARAMETER	(INPUT)	(OUTPUT)	CAPACITANCE	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNIT	
4			C _L = 15 pF	80*	130*		70*		70		MHz	
f _{max}			C _L = 50 pF	55	85		50		50		IVITZ	
tPLH	CLK	Q	C 15 pF		8.1*	12.7*	1*	15*	1	15	20	
tPHL	CLK	Q	C _L = 15 pF		8.1*	12.7*	1*	15*	1	15	ns	
^t PZH		0	C. 45 pF		7.1*	11*	1*	13*	1	13		
tPZL	ŌĒ	Q	C _L = 15 pF		7.1*	11*	1*	13*	1	13	ns	
t _{PHZ}		Q	C _I = 15 pF		7.5*	10.5*	1*	12.5*	1	12.5	ns	
t _{PLZ}	ŌĒ	OE	y	CL = 13 pr		7.5*	10.5*	1*	12.5*	1	12.5	110
t _{PLH}	CLK	Q	C _L = 50 pF		10.6	16.2	1	18.5	1	18.5	ns	
t _{PHL}	OLK	ď	GL = 30 pr		10.6	16.2	1	18.5	1	18.5	115	
^t PZH	<u></u>	Q	C _I = 50 pF		9.6	14.5	1	16.5	1	16.5	ns	
tPZL	ŌĒ	ď	GL = 30 pr		9.6	14.5	1	16.5	1	16.5	115	
^t PHZ	ŌĒ	Q	C _L = 50 pF		10.2	14	1	16	1	16	ns	
t _{PLZ}		<u> </u>	OL = 30 pi		10.2	14	1	16	1	16	115	
tsk(o)			C _L = 50 pF			1.5**				1.5	ns	

^{*} On products compliant to MIL-PRF-38535, this parameter is not production tested.

switching characteristics over recommended operating free-air temperature range, V_{CC} = 5 V \pm 0.5 V (unless otherwise noted) (see Figure 1)

PARAMETER	FROM	то	LOAD	T,	T _A = 25°C		SN54AHC374		SN74AI	UNIT		
PARAMETER	(INPUT)	(OUTPUT)	CAPACITANCE	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNII	
			C _L = 15 pF	130*	185*		110*		110		MHz	
f _{max}			C _L = 50 pF	85	120		75		75		IVITIZ	
t _{PLH}	CLK	Q	C _I = 15 pF		5.4*	8.1*	1*	9.5*	1	9.5	ns	
t _{PHL}	OLIV	Q	CL = 15 pr		5.4*	8.1*	1*	9.5*	1	9.5	115	
^t PZH	ŌE	Q	C _I = 15 pF		5.1*	7.6*	1*	9*	1	9	ns	
^t PZL	OE	Q	GE = 13 bis		5.1*	7.6*	1*	9*	1	9	115	
^t PHZ	- -	Q	C _I = 15 pF		4.6*	6.8*	1*	8*	1	8	ns	
t _{PLZ}	ŌĒ	OE	Q	CL = 15 pr		4.6*	6.8*	1*	8*	1	8	115
^t PLH	CLK	Q	C _I = 50 pF		6.9	10.1	1	11.5	1	11.5	ns	
^t PHL	OLK	Q	CL = 30 pi		6.9	10.1	1	11.5	1	11.5	115	
^t PZH	- -	Q	C _I = 50 pF		6.6	9.6	1	11	1	11	ns	
^t PZL	ŌĒ	Q	OL = 30 pi		6.6	9.6	1	11	1	11	115	
^t PHZ	or	Q	C ₁ = 50 pF		6.1	8.8	1	10	1	10	ns	
^t PLZ	ŌĒ	ų ,	GL = 30 pr		6.1	8.8	1	10	1	10	115	
t _{sk(o)}			C _L = 50 pF			1**				1	ns	

^{*} On products compliant to MIL-PRF-38535, this parameter is not production tested.



^{**} On products compliant to MIL-PRF-38535, this parameter does not apply.

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noise characteristics, V_{CC} = 5 V, C_L = 50 pF, T_A = 25°C (see Note 4)

	PARAMETER	SN7	UNIT		
	PARAMETER	MIN	TYP	MAX	UNIT
V _{OL(P)}	Quiet output, maximum dynamic V _{OL}		0.5	1	V
V _{OL} (V)	Quiet output, minimum dynamic V _{OL}		-0.5	-0.8	V
VOH(V)	Quiet output, minimum dynamic VOH	4			V
VIH(D)	High-level dynamic input voltage	3.5			V
V _{IL(D)}	Low-level dynamic input voltage			1.5	V

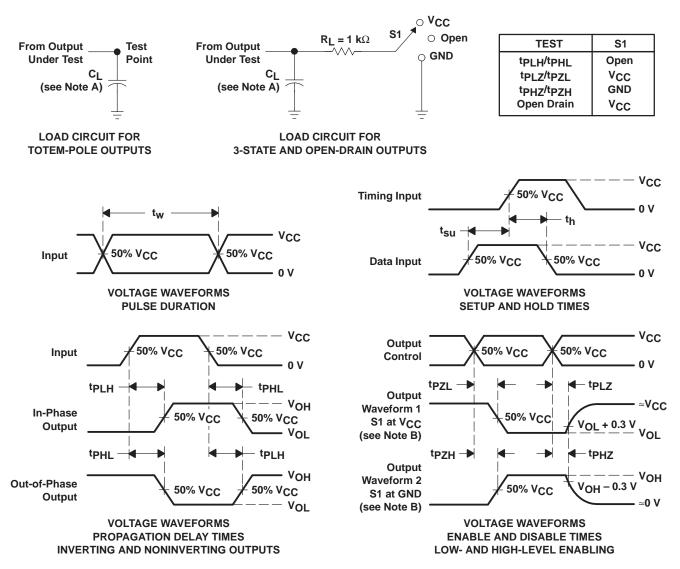
NOTE 4: Characteristics are for surface-mount packages only.

operating characteristics, V_{CC} = 5 V, T_A = 25°C

	PARAMETER	TEST C	ONDITIONS	TYP	UNIT
C _{pd}	Power dissipation capacitance	No load,	f = 1 MHz	32	pF



PARAMETER MEASUREMENT INFORMATION



NOTES: A. C_L includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR \leq 1 MHz, $Z_O = 50 \Omega$, $t_f \leq 3$ ns, $t_f \leq 3$ ns.
- D. The outputs are measured one at a time with one input transition per measurement.

Figure 1. Load Circuit and Voltage Waveforms

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